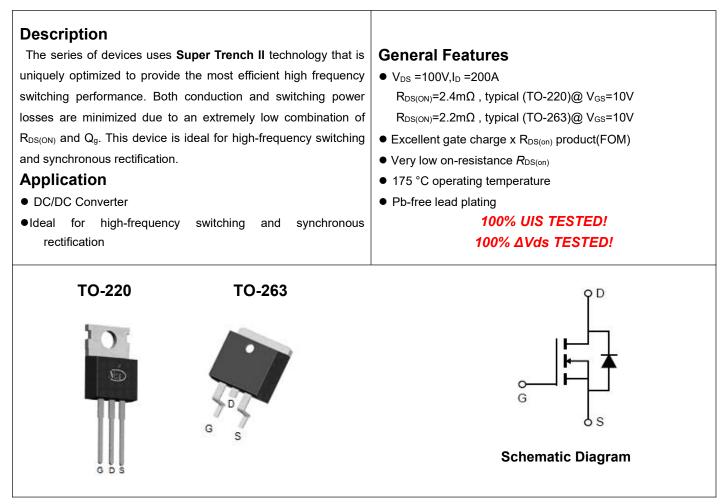


## NCE N-Channel Super Trench II Power MOSFET



### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP026N10	NCEP026N10	TO-220	-	-	-
NCEP026N10D	NCEP026N10D	TO-263	-	-	-

### Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι <sub>D</sub>	200	A
Drain Current-Continuous(Tc=100 ℃)	I <sub>D</sub> (100℃)	142	A
Pulsed Drain Current	I <sub>DM</sub>	800	A
Maximum Power Dissipation	PD	300	W
Derating factor		2	W/°C
Single pulse avalanche energy <sup>(Note 5)</sup>	E <sub>AS</sub>	2300	mJ
Operating Junction and Storage Temperature Range	TJ,Tstg	-55 To 175	°C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	Rejc	0.5	°C <b>/W</b>
Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>0JA</sub>	60	°C <b>/W</b>

### Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition		Min	Тур	Max	Unit
Off Characteristics							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA		100		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>G</sub>	<sub>is</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	Igss	V <sub>GS</sub> =±20V,V <sub>D</sub>	vs=0V	-	-	±100	nA
On Characteristics (Note 3)	I			-			
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =2	50µA	2.0	3.0	4.0	V
Desire Deserves On Otata Desistance		V <sub>GS</sub> =10V, I <sub>D</sub> =100A	TO-220	-	2.4	2.6	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>		TO-263		2.2	2.6	mΩ
Gate resistance	Rg			-	2.5	-	Ω
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =100A			90	-	S
Dynamic Characteristics (Note4)							
Input Capacitance	Clss	- V <sub>DS</sub> =50V,V <sub>GS</sub> =0V, - F=1.0MHz		-	17500	-	PF
Output Capacitance	Coss			-	1100	-	PF
Reverse Transfer Capacitance	Crss			-	50	-	PF
Switching Characteristics (Note 4)				•			
Turn-on Delay Time	t <sub>d(on)</sub>			-	34	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =50V,I <sub>D</sub> =100A $V_{GS}$ =10V,R <sub>G</sub> =1.6Ω		-	27	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>			-	78	-	nS
Turn-Off Fall Time	t <sub>f</sub>			-	30	-	nS
Total Gate Charge	Qg		1004	-	240	-	nC
Gate-Source Charge	Q <sub>gs</sub>	- V <sub>DS</sub> =50V,I <sub>D</sub> =100A, - V <sub>GS</sub> =10V		-	75		nC
Gate-Drain Charge	Q <sub>gd</sub>			-	60		nC
Drain-Source Diode Characteristics	I						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =100A		-		1.2	V
Diode Forward Current (Note 2)	Is			-	-	200	Α
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> =	: 100A	-	101	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>		-	280	-	nC

#### Notes:

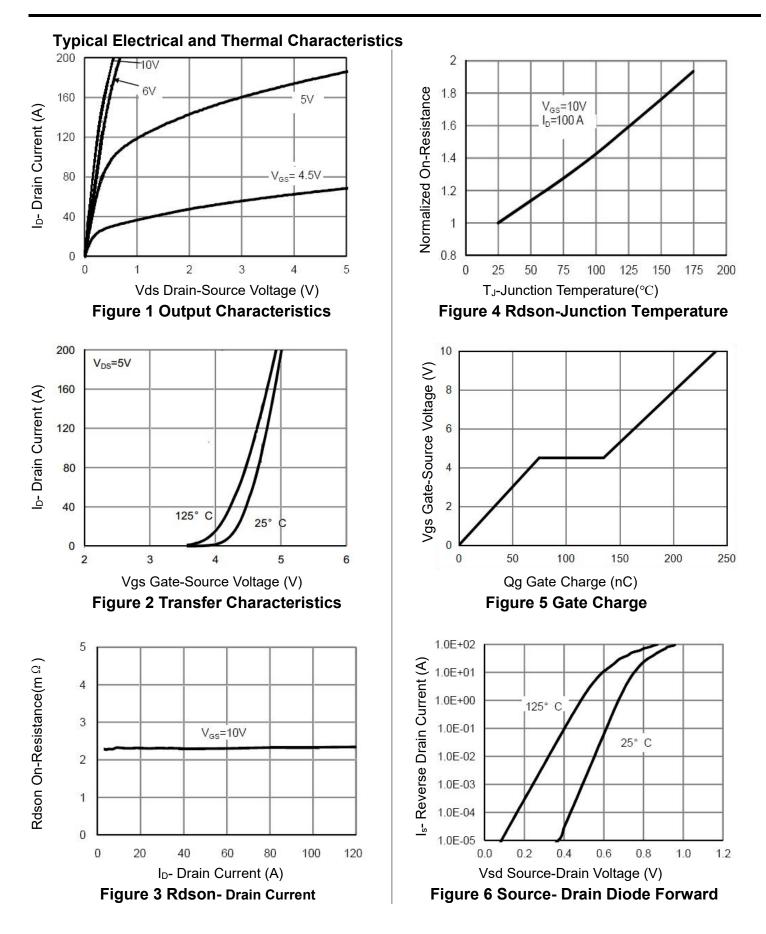
1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. The value of  $R_{0JA}$  is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with  $T_A = 25^{\circ}$  C. The Power dissipation  $P_{DSM}$  is based on R  $_{0JA}$  and the maximum allowed junction temperature of 150° C. The value in any given application depends on the user's specific board design, and the maximum temperature of 175° C may be used if the PCB allows it.

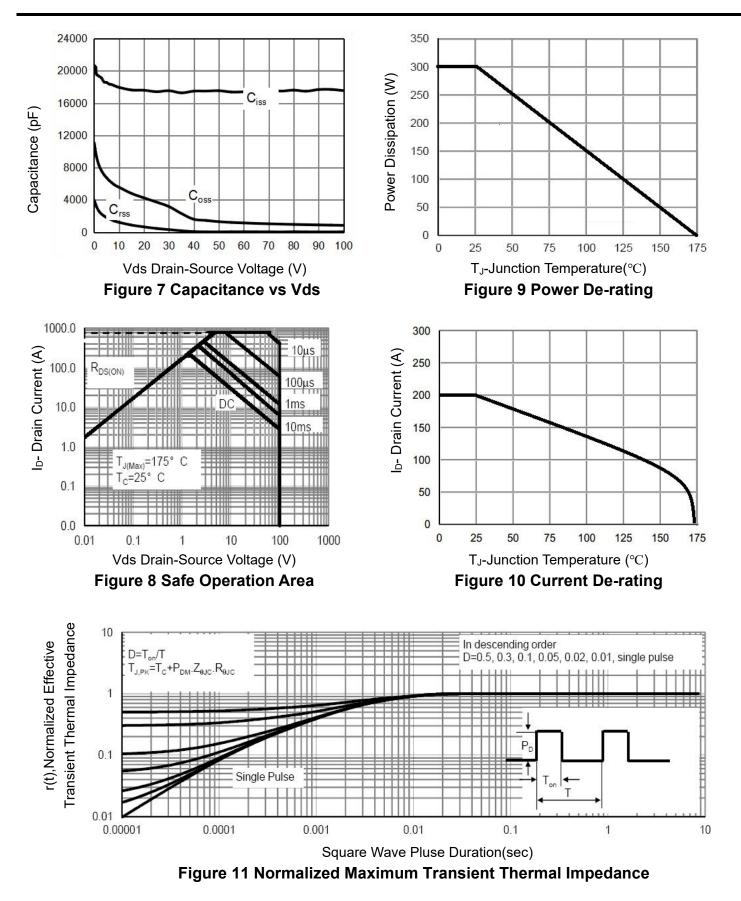
3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production

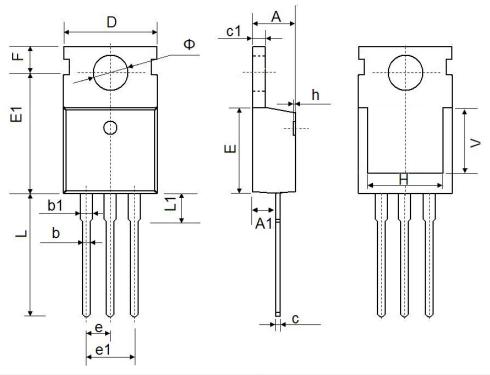
5. EAS condition : Tj=25  $^\circ\!\mathrm{C}$  ,V\_{DD}=50V ,V\_G=10V ,L=0.5mH ,Rg=25  $\Omega$ 



## NCEP026N10, NCEP026N10D



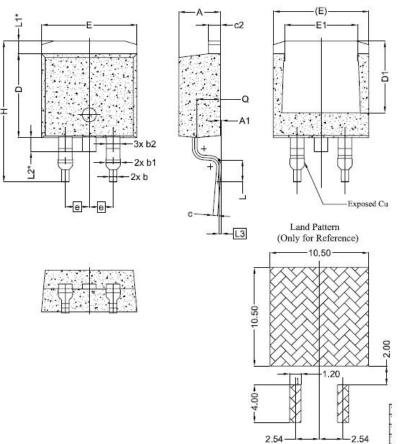
## TO-220-3L Package Information



Symbol	Dimensions In Millimeters		Dimension	s In Inches	
Symbol	Min.	Max.	Min.	Max.	
A	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
с	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100	TYP.	
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	6.900	6.900 REF.		REF.	
Ф	3.400	3.800	0.134	0.150	

# NCEP026N10, NCEP026N10D

## TO-263-2L Package Information



## NCEP026N10, NCEP026N10D

SYMBOL	DIMENSIONS				
SYMBOL	MIN,	NOM.	MAX.		
А	4.24	4.44	4.64		
A1	0.00	0.10	0,25		
b	0,70	0.80	0.90		
b1	1.20	1,55	1,75		
b2	1,20	1,45	1,70		
с	0.40	0.50	0.60		
c2	1,15	1,27	1,40		
D	8.82	8.92	9.02		
D1	6.86	7.65			
E	9,96	10,16	10,36		
E1	6.89	7.77	7,89		
е		2.54 BSC			
н	14,61	15,00	15,88		
L	1.78	2.32	2.79		
L1	1.36 REF.				
L2	1.50 REF.				
L3	0.25 BSC				
Q	2,30	2,48	2.70		

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